

NPN Transistors



Part Number	Microsemi Division	Package Outline	Type	Mil Spec	Data Sheet ID	PD (W)	IC (A)	Vcbo (V)	Vceo (V)	Vebo (V)	VCE(sat) (V)	@ IC (mA)	HFE min (dB)	HFE max (dB)
2N5685	PPC, Inc.	TO-3	STD		23464	300	50	60	60	5	1	25	15	60
2N5686	PPC, Inc.	TO-3	STD		23465	300	50	80	80	5	1	25	15	60
2N6322	PPC, Inc.	TO-3	STD		23546	350	30	300	200	5	1.5	5	40	150
2N6324	PPC, Inc.	TO-63	STD		23548	350	30	300	200	5	1.5	5	40	150
2N6323	PPC, Inc.	TO-3	STD		23547	350	30	400	300	5	1.5	5	30	150
2N6325	PPC, Inc.	TO-63	STD		23549	350	30	400	300	5	1.5	5	30	150
2N5587	PPC, Inc.	TO-114	STD		23390	350	80	120	120	6	2	80	10	30
2N5588	PPC, Inc.	TO-114	STD		23391	350	80	160	160	6	2	80	10	30
2N4865	PPC, Inc.	TO-114	STD		23224	350	90	100	80	8	2.5	70	10	40
2N5250	PPC, Inc.	TO-114	STD		23337	350	90	120	100	10	2.5	70	10	40
2N4866	PPC, Inc.	TO-114	STD		23225	350	90	140	120	8	2.5	70	10	40
2N5251	PPC, Inc.	TO-114	STD		23338	350	90	180	150	10	2.5	70	10	40

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Section Organization: NPN Transistor Parametric Section is organized by ascending PD (watts), followed by ascending IC (amps), and then by Part Number

General Notes:

1. Information on contacting Microsemi Divisions can be obtained on the back cover of this catalog
2. For detailed VCE(sat) data refer to the product datasheets by using the fax on demand system or contacting the Microsemi manufacturing division.
4. Datasheets can be obtained from Microsemi's Website or Fax on Demand System by specifying the Data Sheet ID